



SI5314-H / SI5314-H(B)

IRED

Features

- Colorless transparency lens type
- $\phi 5\text{mm}(\text{T}-13/4)$ all plastic mold type
- Low power consumption
- High radiant intensity

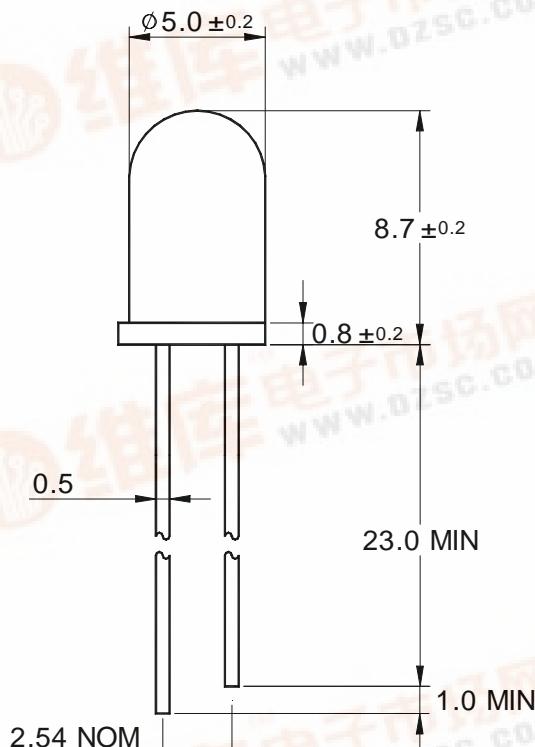
Applications

- Infrared remote control and free air transmission systems with low forward voltage and comfortable radiation angle requirements in combination with PIN photodiodes or phototransistors.

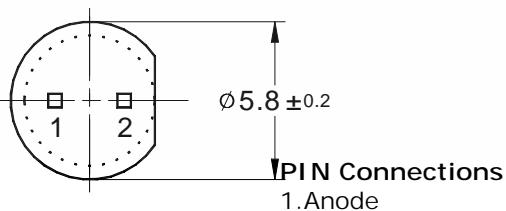
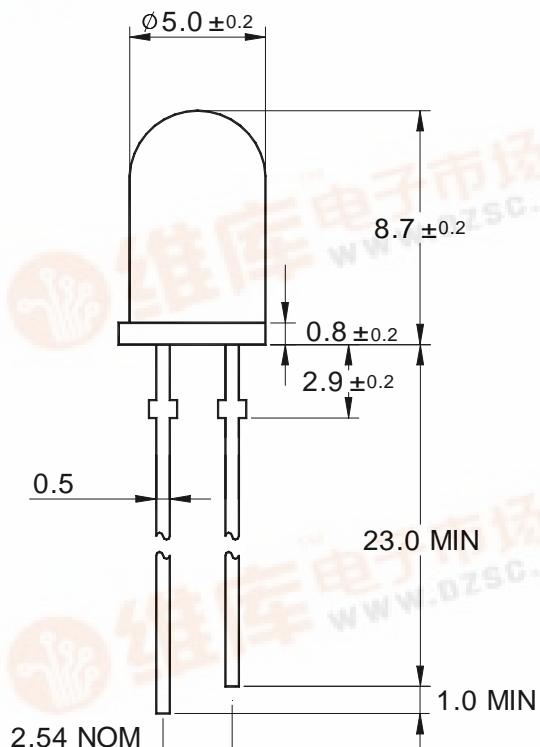
Outline Dimensions

unit : mm

STRAIGHT TYPE



STOPPER TYPE



SI5314-H / SI5314-H(B)

Absolute maximum ratings

| Characteristic | Symbol | Ratings | Unit |
|--------------------------------------|------------------|-------------------|------|
| Power Dissipation | P _D | 150 | mW |
| Forward Current | I _F | 100 | mA |
| * ¹ Peak Forward Current | I _{FP} | 1 | A |
| Reverse Voltage | V _R | 4 | V |
| Operating Temperature | T _{opr} | -25 85 | |
| Storage Temperature | T _{stg} | -30 100 | |
| * ² Soldering Temperature | T _{sol} | 260 for 5 seconds | |

*1.Duty ratio = 1/16, Pulse width = 0.1ms

*2.Keep the distance more than 2.0mm from PCB to the bottom of IRED package

Electrical Characteristics

| Characteristic | Symbol | Test Condition | Min. | Typ. | Max. | Unit |
|---------------------------|------------------|-----------------------|------|------|------|-------|
| Forward Voltage | V _F | I _F = 50mA | - | 1.3 | 1.7 | V |
| Radiant Intensity | I _E | I _F = 50mA | 15 | 35 | - | mW/Sr |
| Peak Wavelength | λ _P | I _F = 50mA | - | 950 | - | nm |
| Spectrum Bandwidth | | I _F = 50mA | - | 50 | - | nm |
| Reverse Current | I _R | V _R =4V | - | - | 10 | uA |
| * ³ Half angle | θ ^{1/2} | I _F = 50mA | - | ±25 | - | deg |

*3. θ_{1/2} is the off-axis angle where the luminous intensity is 1/2 the peak intensity

SI5314-H / SI5314-H(B)

Characteristic Diagrams

Fig. 1 I_F - V_F

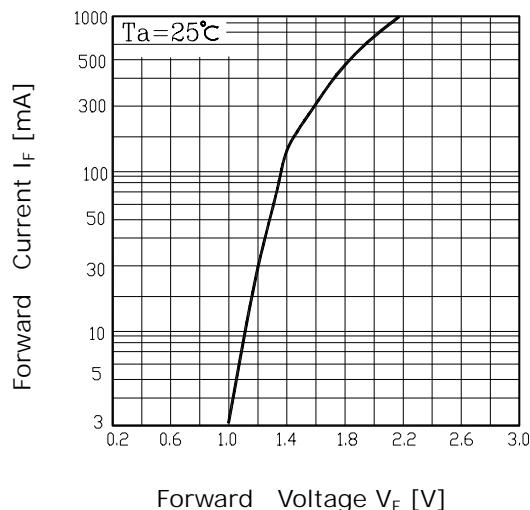


Fig. 2 I_E - I_F

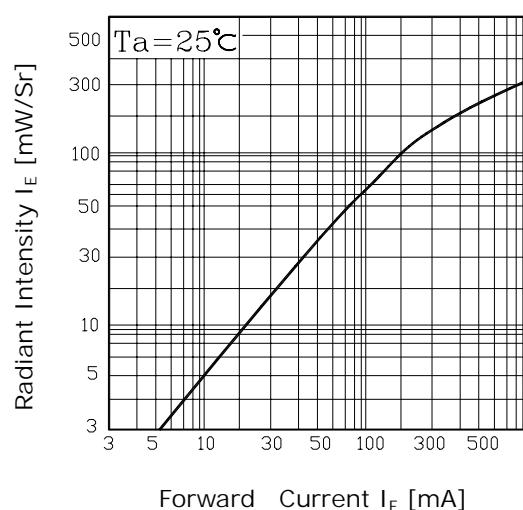


Fig. 3 I_F - T_a

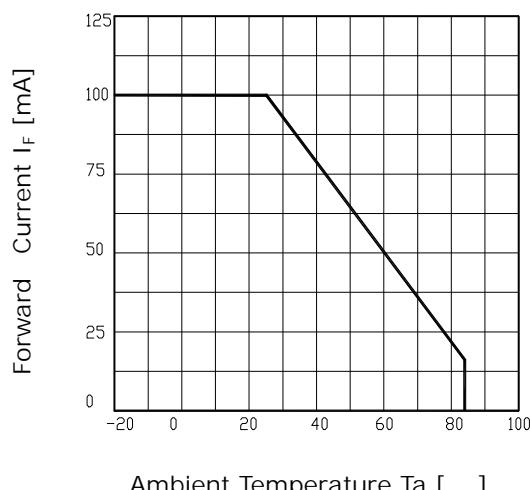


Fig.4 Spectrum Distribution

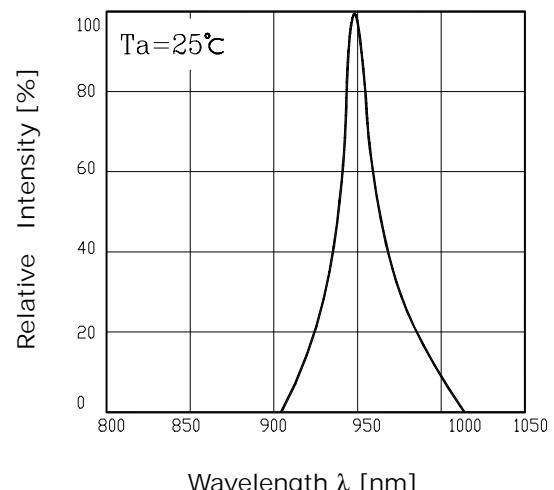


Fig. 5 Radiation Diagram

